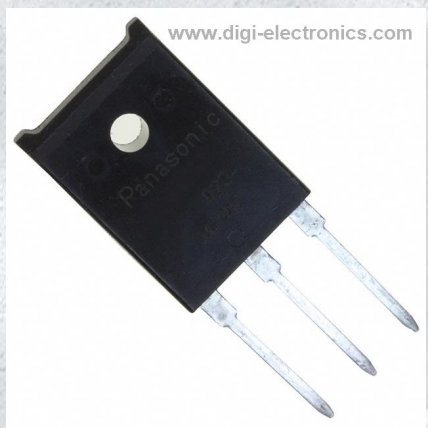
2SC3507 Datasheet



https://www.DiGi-Electronics.com

DiGi Electronics Part Number	2SC3507-DG
Manufacturer	Panasonic Electronic Components
Manufacturer Product Number	2SC3507
Description	TRANS NPN 800V 5A TOP-3F
Detailed Description	Bipolar (BJT) Transistor NPN 800 V 5 A 6MHz 3 W Through Hole TOP-3F-A1

Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
2SC3507	Panasonic Electronic Components
Series:	Product Status:
-	Obsolete
Transistor Type:	Current - Collector (Ic) (Max):
NPN	5 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ Ib, Ic:
800 V	1.5V @ 600mA, 3A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
50µA (ICBO)	6 @ 3A, 5V
Power - Max:	Frequency - Transition:
3 W	6MHz
Operating Temperature:	Mounting Type:
150°C (TJ)	Through Hole
Package / Case:	Supplier Device Package:
TOP-3F	TOP-3F-A1
Base Product Number:	
2SC350	

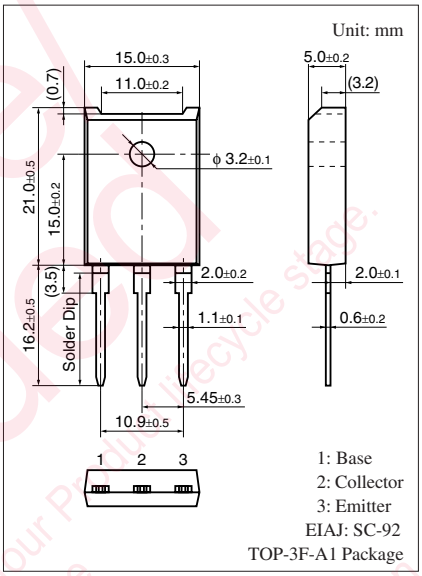
Environmental & Export classification

Moisture Sensitivity Level (MSL):	ECCN:
1 (Unlimited)	EAR99
HTSUS:	
8541.29.0095	

2SC3507

Silicon NPN triple diffusion planar type

For high breakdown voltage high-speed switching



■ Features

- High-speed switching
- High collector-base voltage (Emitter open) V_{CBO}
- Satisfactory linearity of forward current transfer ratio h_{FE}
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25°C$

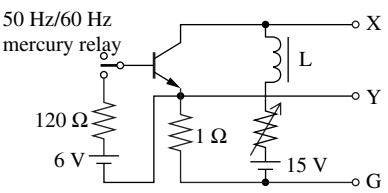
Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	1 000	V
Collector-emitter voltage (E-B short)	V_{CES}	1 000	V
Collector-emitter voltage (Base open)	V_{CEO}	800	V
Emitter-base voltage (Collector open)	V_{EBO}	7	V
Collector current	I_C	5	A
Base current	I_B	3	A
Peak collector current	I_{CP}	10	A
Collector power dissipation	P_C	80	W
$T_a = 25°C$		3.0	
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	−55 to +150	°C

■ Electrical Characteristics $T_C = 25°C \pm 3°C$

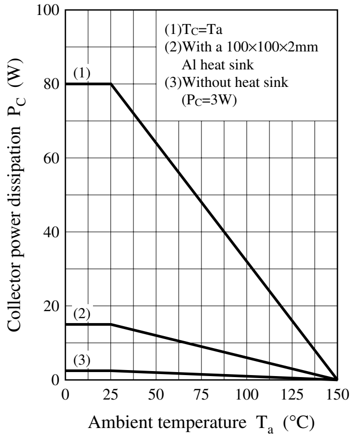
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter sustaining voltage *	$V_{CEO(SUS)}$	I_C = 0.5 A, L = 50 mH	800			V
Collector-base cutoff current (Emitter open)	I_{CBO}	V_{CB} = 1 000 V, I_E = 0			50	µA
Emitter-base cutoff current (Collector open)	I_{EBO}	V_{EB} = 7 V, I_C = 0			50	µA
Forward current transfer ratio	h_{FE}	V_{CE} = 5 V, I_C = 3 A	6			—
Collector-emitter saturation voltage	$V_{CE(sat)}$	I_C = 3 A, I_B = 0.6 A			1.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	I_C = 3 A, I_B = 0.6 A			1.5	V
Transition frequency	f_T	V_{CE} = 5 V, I_C = 0.5 A, f = 1 MHz		6		MHz
Turn-on time	t_{on}	I_C = 3 A			1.0	µs
Storage time	t_{stg}	I_{B1} = 0.6 A, I_{B2} = −1.2 A			2.5	µs
Fall time	t_f	V_{CC} = 250 V			0.5	µs

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

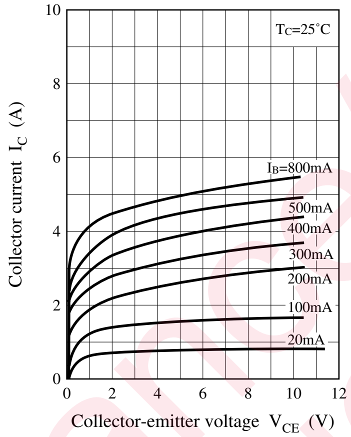
2. *: $V_{CEO(SUS)}$ test circuit



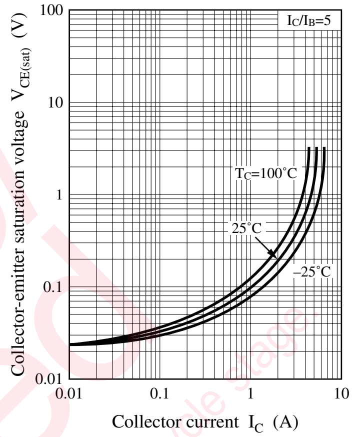
P_C — T_a



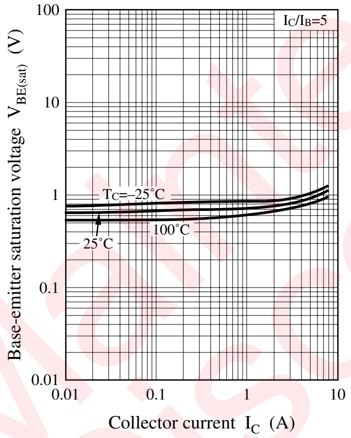
I_C — V_{CE}



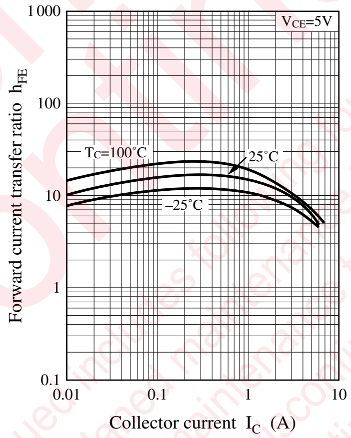
$V_{CE(sat)}$ — I_C



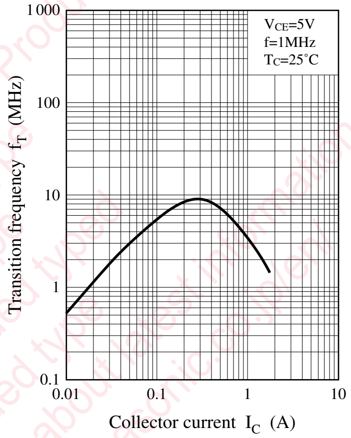
$V_{BE(sat)}$ — I_C



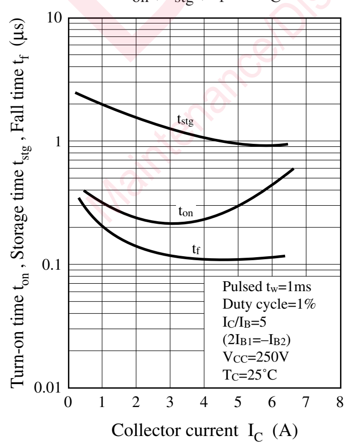
h_{FE} — I_C



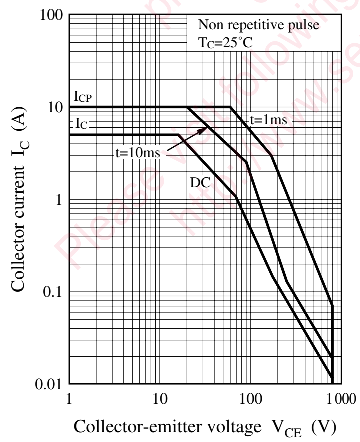
f_T — I_C



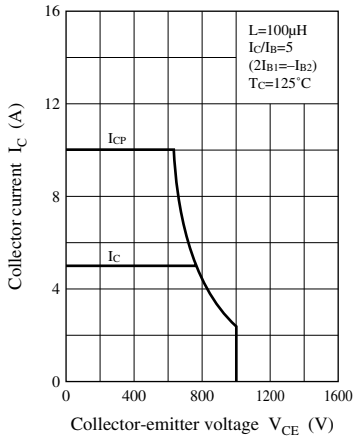
t_{on} , t_{stg} , t_f — I_C



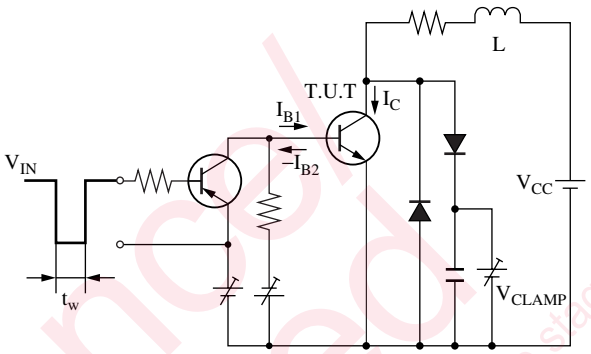
Safe operation area



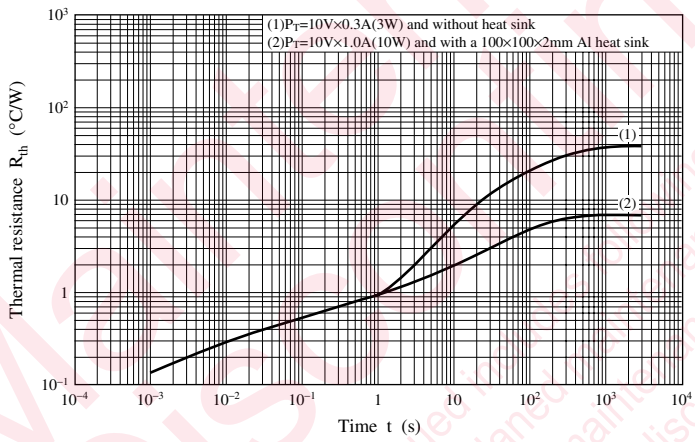
Safe operation area (Reserve bias)



Safe operation area (Reserve bias) measurement circuit



R_{th} — t



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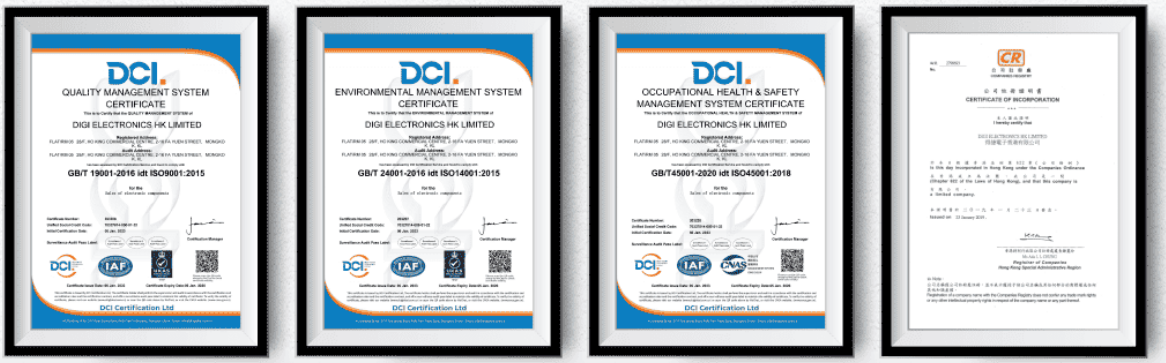

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